





#### **N-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on) max</sub>	Ι <sub>D</sub> Τ <sub>A</sub> = +25°C
30V	60mΩ @ V <sub>GS</sub> = 4.5V	3.2A
	80mΩ @ V <sub>GS</sub> = 2.5V	2.7A
	130mΩ @ V <sub>GS</sub> = 1.5V	2.1A

#### **Description**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

- General Purpose Interfacing Switch
- Power Management Functions

Analog Switch

# Features

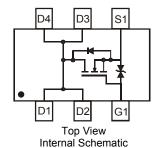
- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- ESD Protected Gate
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT26
- Case Material Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
  Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- · Weight: 0.015 grams (approximate)







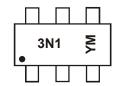
### Ordering Information (Note 4 & 5)

Part Number	Qualification	Case	Packaging
DMN3115UDM-7	Commercial	SOT26	3,000/Tape & Reel
DMN3115UDMQ-7	Automotive	SOT26	3,000/Tape & Reel
DMN3115UDM-13	Commercial	SOT26	10,000/Tape & Reel
DMN3115UDMQ-13	Automotive	SOT26	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



3N1 = Marking Code YM = Date Code Marking Y = Year (ex: U = 2007) M = Month (ex: 9 = September)

Date Code Key

Year	2007	20	800	2009	2010	2	011	2012	2013	2	014	2015
Code	U	'	V	W	X		Υ	Z	Α		В	С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	a	0	N	П



#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	$V_{DSS}$	30	V
Gate-Source Voltage	$V_{GSS}$	±8	V
Drain Current (Note 6)	I <sub>D</sub>	3.2	Α
Pulsed Drain Current (Note 6)	I <sub>DM</sub>	12.8	А

#### **Thermal Characteristics**

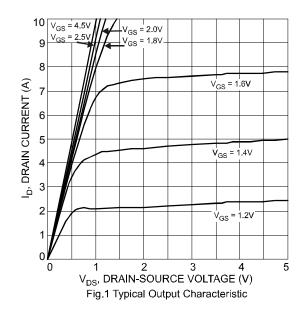
Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 6)	$P_{D}$	900	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	139	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

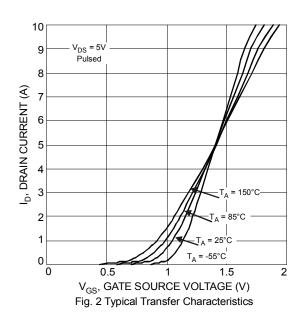
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 100\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	1	μΑ	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>		_	±5	μΑ	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.5		1.0	>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
			40	60		$V_{GS} = 4.5V, I_D = 6A$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	_	50	80		$V_{GS} = 2.5V, I_D = 2A$	
			76	130		$V_{GS} = 1.5V, I_D = 1.0A$	
Forward Transfer Admittance	Y <sub>fs</sub>		8	_	S	V <sub>DS</sub> =10V, I <sub>D</sub> = 6A	
Diode Forward Voltage (Note 7)	$V_{SD}$		0.7	1.1	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 2A	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C <sub>iss</sub>		476	_	pF	45)()(	
Output Capacitance	Coss		77	_	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	59	_	pF	11 - 1.UIVIIIZ	

Notes:

- 6. Device mounted on FR-4 PCB, minimum recommended pad layout on 2oz. Copper pads.
- 7. Short duration pulse test used to minimize self-heating effect.







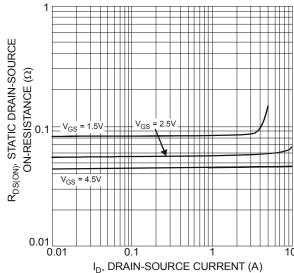


Fig. 3 On-Resistance vs. Drain Current & Gate Voltage

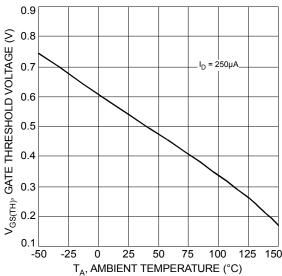


Fig. 5 Gate Threshold Variation vs. Ambient Temperature

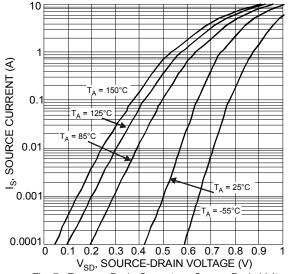


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

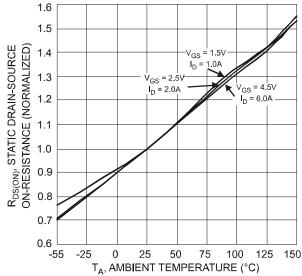
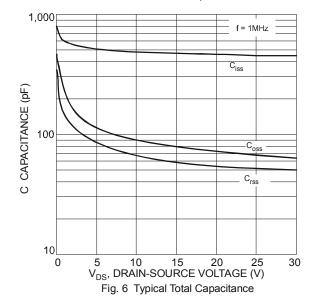


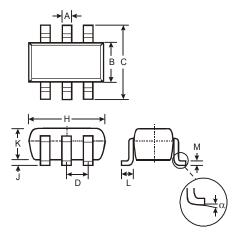
Fig. 4 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature





## **Package Outline Dimensions**

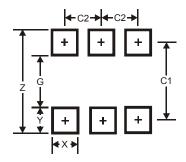
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT26							
Dim	Min	Max	Тур				
Α	0.35	0.50	0.38				
В	1.50	1.70	1.60				
С	2.70	3.00	2.80				
D	_		0.95				
Н	2.90	3.10	3.00				
J	0.013	0.10	0.05				
K	1.00	1.30	1.10				
L	0.35	0.55	0.40				
M	0.10	0.20	0.15				
α	0°	8°	_				
All Dimensions in mm							

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95



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